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Accepted papers will be submitted for inclusion into IEEE Xplore Digital Library according to conference #58183, 2023 IEEE Latin American Electron Devices Conference (LAEDC), subject to meeting IEEE Xplore’s scope and quality requirements. The best papers presented in the conference will be considered for publication in a special issue of the Journal of the Electron Devices Society (EDS).

CONTACT
LAEDC@ieee.org

IMPORTANT DATES

Paper submission:
Mar 31, 2023

Author notification
May 1, 2023

CONFERENCE DATES:
JULY 3-5 2023

Topics of interest include

- All electron-based devices
- Electron Devices for Quantum Computing
- RF-MMW-5G
- Semiconductor-, MEMS- and Nanotechnologies
- Packaging, 3D integration
- Sensors and actuators
- Display technology
- Modeling and simulation
- Reliability and yield
- Device characterization
- Reliability
- Agrivoltaics
- Biomedical Devices
- Circuit-device interaction
- Novel materials and process modules
- Technology roadmaps
- Electron device engineering education
- Electron device outreach
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- STEM Initiatives
- Energy harvesting
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